

T-51-17

CD54/74HC4511 CD54/74HCT4511

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE, (V _{CC}): (Voltages referenced to ground)	-0.5 to +7 V
DC INPUT DIODE CURRENT, I _{IK} (FOR V _I < -0.5 V OR V _I > V _{CC} +0.5 V)	±20 mA
DC OUTPUT DIODE CURRENT, I _{OK} (FOR V _O < -0.5 V OR V _O > V _{CC} +0.5 V)	±20 mA
DC DRAIN CURRENT, PER OUTPUT (I _O) (FOR -0.5 V < V _O < V _{CC} +0.5 V)	±25 mA
DC V _{CC} OR GROUND CURRENT (I _{CC})	±50 mA
POWER DISSIPATION PER PACKAGE (P ₀):		
For T _A = -40 to +60°C (PACKAGE TYPE E)	500 mW
For T _A = +60 to +85°C (PACKAGE TYPE E)	Derate Linearly at 8 mW/°C to 300 mW
For T _A = -55 to +100°C (PACKAGE TYPE F,H)	500 mW
For T _A = +100 to +125°C (PACKAGE TYPE F,H)	Derate Linearly at 8 mW/°C to 300 mW
For T _A = -40 to +70°C (PACKAGE TYPE M)	400 mW
For T _A = +70 to +125°C (PACKAGE TYPE M)	Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T _A):		
PACKAGE TYPE F,H	-55 to +125°C
PACKAGE TYPE E,M	-40 to +85°C
STORAGE TEMPERATURE (T _{stg})	-65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max.	+265°C
Unit inserted into a PC Board (min. thickness 1/16 in., 1.59 mm) with solder contacting lead tips only	+300°C

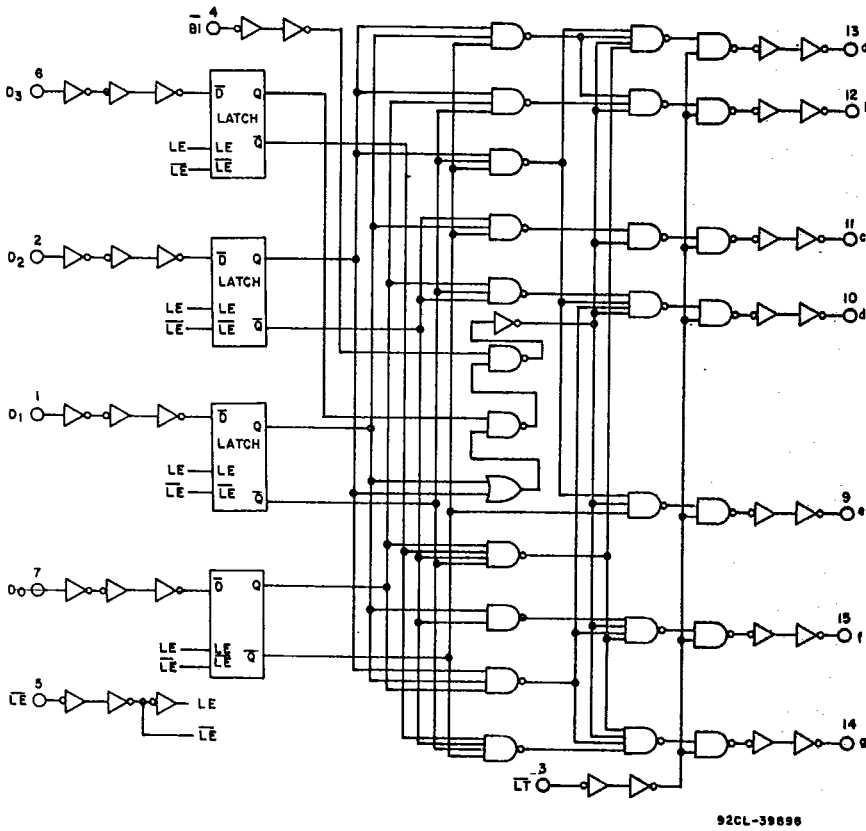


Fig. 1 - Logic diagram.

HARRIS SEMICONDUCTOR 27E D 4302271 0017977 ? HAS

CD54/74HC4511
CD54/74HCT4511

STATIC ELECTRICAL CHARACTERISTICS

HARRIS SEMICOND SECTOR 27E D 4302271 0017978 9 HAS

CHARACTERISTIC	CD74HC4511/CD54HC4511										CD74HCT4511/CD54HCT4511										UNITS				
	TEST CONDITIONS			74HC/54HC TYPES			74HC TYPES			54HC TYPES			TEST CONDITIONS			74HCT/54HCT TYPES			74HCT TYPES			54HCT TYPES			
	V _I V	I _O mA	V _{CC} V	+25°C			-40/ +85°C			-55/ +125°C			V _I V	V _{CC} V	+25°C			-40/ +85°C				-55/ +125°C			
				Min	Typ	Max	Min	Max	Min	Max	Min	Max			Min	Typ	Max	Min	Max	Min		Max			
High-Level Input Voltage	V _{IH}			2	1.5	—	—	1.5	—	1.5	—	—	—	4.5	to	2	—	—	2	—	2	—	—	V	
				4.5	3.15	—	—	3.15	—	3.15	—	—	—	5.5											
				6	4.2	—	—	4.2	—	4.2	—	—	—												
Low-Level Input Voltage	V _{IL}			2	—	—	0.5	—	0.5	—	0.5	—	—	4.5	to	—	—	0.8	—	0.8	—	0.8	—	V	
				4.5	—	—	1.35	—	1.35	—	1.35	—	—	5.5											
				6	—	—	1.8	—	1.8	—	1.8	—	—												
High-Level Output Voltage	V _{OH}	V _{IL} or V _{IH}	-0.02	2	1.9	—	—	1.9	—	1.9	—	V _{IL} or V _{IH}	V _{IL} or V _{IH}	4.5	4.4	—	—	4.4	—	4.4	—	4.4	—	V	
CMOS Loads				6	5.9	—	—	5.9	—	5.9	—														
TTL Loads																									
Non-Standard Output	V _{IL} or V _{IH}		-7.5 -10	4.5 6	3.98 5.48	—	—	3.84 5.34	—	3.7 5.2	—	V _{IL} or V _{IH}	V _{IL} or V _{IH}	4.5	3.98	—	—	3.84	—	3.7	—	3.7	—	V	
Low-Level Output Voltage	V _{OL}	V _{IL} or V _{IH}	0.02	2	—	—	0.1	—	0.1	—	0.1	V _{IL} or V _{IH}	V _{IL} or V _{IH}	4.5	—	—	0.1	—	0.1	—	0.1	—	0.1	V	
CMOS Loads				4.5	—	—	0.1	—	0.1	—	0.1														
				6	—	—	0.1	—	0.1	—	0.1														
TTL Loads																									
Standard Output	V _{IL} or V _{IH}		4 5.2	4.5 6	— —	— —	0.26 0.26	— —	0.33 0.33	— —	0.4 0.4	V _{IL} or V _{IH}	V _{IL} or V _{IH}	4.5	—	—	0.26	—	0.33	—	0.4	—	0.4	V	
Input Leakage Current	I _I	V _{CC} or Gnd		6	—	—	±0.1	—	±1	—	±1	Any Voltage Between V _{CC} & Gnd	5.5	—	—	±0.1	—	±1	—	±1	—	±1	μA		
Quiescent Device Current	I _{CC}	V _{CC} or Gnd	0	6	—	—	8	—	80	—	160	V _{CC} or Gnd	5.5	—	—	8	—	80	—	160	—	160	μA		
Additional Quiescent Device Current per input pin: 1 unit load	ΔI _{CC} *											V _{CC} -2.1	4.5 to 5.5	—	100	360	—	450	—	490	—	490	μA		

*For dual-supply systems theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

HCT Input Loading Table

Input	Unit Loads*
LT, LE	1.5
BI, Dn	0.3

*Unit Load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 360 μA max. @ 25°C.

T-51-17

CD54/74HC4511
CD54/74HCT4511

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For T _A =Full Package Temperature Range) V _{CC} *	2 4.5	6 5.5	V
DC Input or Output Voltage, V _I , V _O	0	V _{CC}	V
Operating Temperature, T _A : CD74 Types CD54 Types	-40 -55	+85 +125	°C
Input Rise and Fall Times, t _r , t _f : at 2 V at 4.5 V at 6 V	0 0 0	1000 500 400	ns

*Unless otherwise specified, all voltages are referenced to Ground.

SWITCHING CHARACTERISTICS (V_{CC}=5 V, T_A=25° C, Input t_r, t_f=6 ns)

CHARACTERISTIC	C _L (pF)	TYPICAL VALUES		UNITS	
		HC	HCT		
Propagation Delay: D _n to Output	t _{PLH} t _{PHL}	15	25	ns	
\overline{LE} to Output	t _{PLH} t _{PHL}	15	23		
\overline{BI} to Output	t _{PLH} t _{PHL}	15	18		
\overline{LT} to Output	t _{PLH} t _{PHL}	15	13		
Power Dissipation Capacitance*	C _{PD}	—	114	110	pF

*C_{PD} is used to determine the dynamic power consumption, per package.

$P_D = C_{PD} V_{CC}^2 f_i + \sum C_L V_{CC}^2 f_o$ where f_i = input frequency
 f_o = output frequency
 C_L = output load capacitance
 V_{CC} = supply voltage.

PRE-REQUISITE FOR SWITCHING FUNCTION

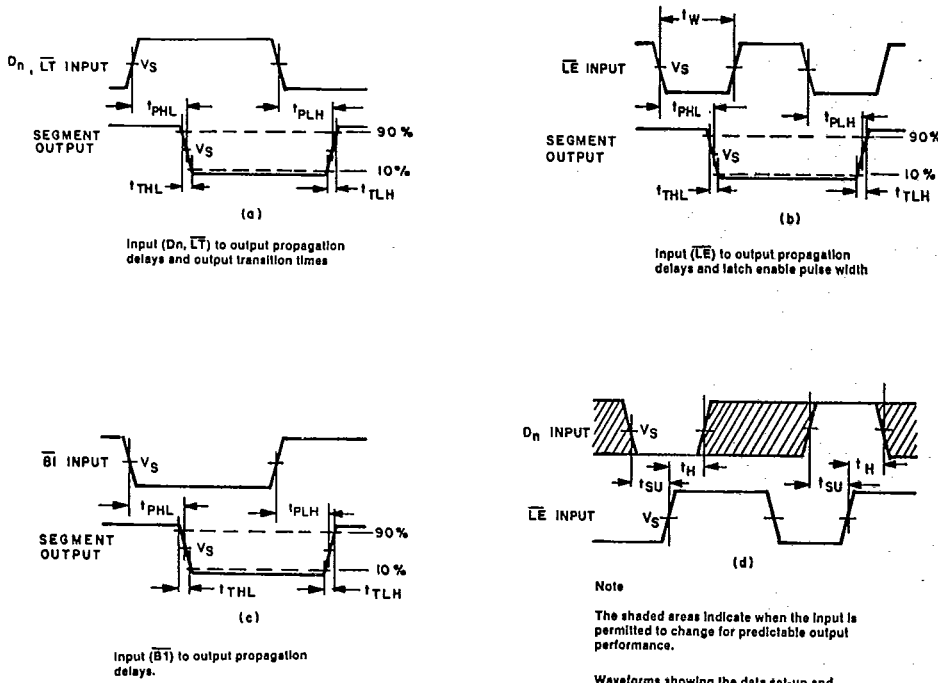
CHARACTERISTIC	TEST CONDITIONS V _{CC} (V)	LIMITS												UNITS
		25° C				-40° C to +85° C				-55° C to +125° C				
		HC		HCT		74HC		74HCT		54HC		54HCT		
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Setup Time, D _n to \overline{LE}	2	60	—	—	—	75	—	—	—	90	—	—	—	ns
	4.5	12	—	12	—	15	—	15	—	18	—	18	—	
	6	10	—	—	—	13	—	—	—	15	—	—	—	
Hold Time, D _n to \overline{LE}	2	3	—	—	—	3	—	—	—	3	—	—	—	ns
	4.5	3	—	5	—	3	—	5	—	3	—	5	—	
	6	3	—	—	—	3	—	—	—	3	—	—	—	
Latch Enable Pulse Width, t _w	2	80	—	—	—	100	—	—	—	120	—	—	—	MHz
	4.5	16	—	16	—	20	—	20	—	24	—	24	—	
	6	14	—	—	—	17	—	—	—	20	—	—	—	

HARRIS SEMICONDUCTOR 27E D 4302271 0017979 0 HAS

CD54/74HC4511
CD54/74HCT4511

SWITCHING CHARACTERISTICS (C_L=50 pF, Input t_r,t_f=6 ns)

CHARACTERISTIC	V _{CC}	LIMITS												UNITS	
		25°C				-40°C to +85°C				-55°C to +125°C					
		HC		HCT		74HC		74HCT		54HC		54HCT			
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.		
Propagation Delay, D _n to Output	t _{PLH}	2	—	300	—	—	—	375	—	—	—	450	—	—	ns
	t _{PHL}	4.5	—	60	—	60	—	75	—	75	—	90	—	90	
		6	—	51	—	—	—	64	—	—	—	77	—	—	
$\overline{\text{LE}}$ to Output	t _{PLH}	2	—	270	—	—	—	340	—	—	—	405	—	—	ns
	t _{PHL}	4.5	—	54	—	54	—	68	—	68	—	81	—	81	
		6	—	46	—	—	—	58	—	—	—	69	—	—	
$\overline{\text{BI}}$ to Output	t _{PLH}	2	—	220	—	—	—	275	—	—	—	330	—	—	ns
	t _{PHL}	4.5	—	44	—	44	—	55	—	55	—	66	—	66	
		6	—	37	—	—	—	47	—	—	—	56	—	—	
$\overline{\text{LT}}$ to Output	t _{PLH}	2	—	160	—	—	—	200	—	—	—	240	—	—	ns
	t _{PHL}	4.5	—	32	—	33	—	40	—	41	—	48	—	50	
		6	—	27	—	—	—	34	—	—	—	41	—	—	
Transition Time	t _{THL}	2	—	75	—	—	—	95	—	—	—	110	—	—	ns
	t _{TLH}	4.5	—	15	—	15	—	19	—	19	—	22	—	22	
		6	—	13	—	—	—	16	—	—	—	19	—	—	
Input Capacitance	C _i		—	10	—	10	—	10	—	10	—	10	—	10	pF



	54/74HC	54/74HCT
Input Level	V _{CC}	3 V
Switching Voltage, V _s	50% V _{CC}	1.3 V

Fig. 2 - AC waveforms.

92CM-39899

HARRIS SEMICONDUCTOR 27E D 4302271 0017980 7 HAS